

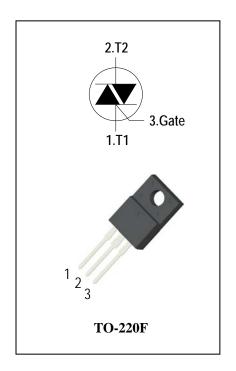
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology, guaranteed maximum junction temperature 150° C. The ADT4CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, Rectifier-fed DC inductive loads e.g.DC motors and solenoids, motor speed controllers. The heatsink can be reduced, compared to traditional triacs, according to the high performance at given junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 4A)
- ◆ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Depotitive Deals Off State Voltage	Ti = 25°C	ADT4CH60F	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADT4CH80F	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T _C = 120°C		4	Α
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		40/42	Α
l ² t	I ² t for fusing	tp=10ms		8	A ² s
-11/-14	Critical rate of rise of on-state	ate $F = 120 \text{ Hz Tj} = 150^{\circ}\text{C}$ $I_G = 2 \text{ x } I_{GT}$, $\text{tr} \le 100 \text{ ns}$		50	A/µs
dl/dt	current				
I_{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C



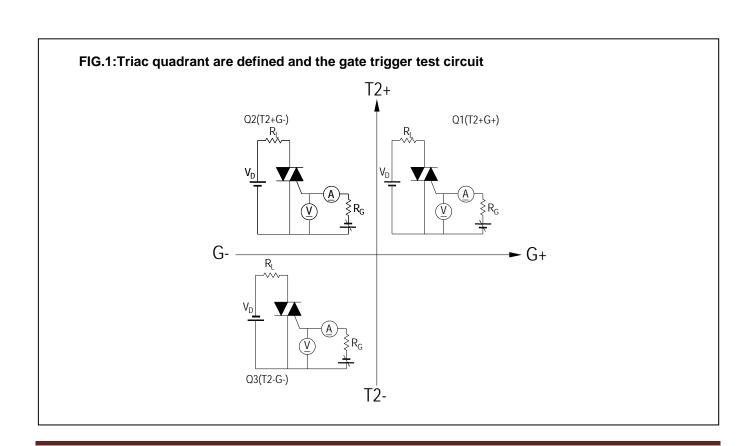


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Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		AD	ADT4CH60F/80F		Unit	
					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		V _{DRM} = V _{RRM} , Tj = 25°C		5		uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 150$ °C	Max.	1.75			mA
V _{TM}	Peak On-S	tate Voltage	I_{TM} = 5.5A, t_p = 380 μ s	Max.	1.55			V
V_{GD}	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	1/ 40V D 000	Max.	1.5			٧
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$		10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	45	60	mA
ΙL	Q1-Q3	Latabia a Ocument	1 401	Max.	20	50	70	mA
	Q2	Latching Current	I _G = 1.2 I _{GT}		35	70	100	
dV/dt			$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		V_D =400V Tj = 150°C (dl/dt)c=-1.7A/ms	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	4.0		°C/W		
R _{th(j-a})	Junction to ambient		Max.	60			°C/W	



ADV

FIG.2: Maximum on-state power dissipation

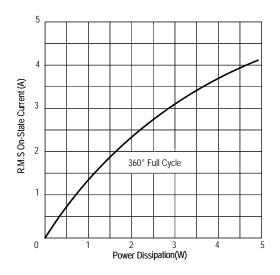


FIG.4: Maximum transient thermal impedance

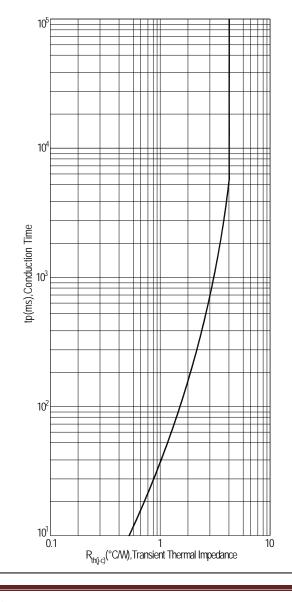


FIG.3: Typical RMS on-state current VS Allowable case Temperature

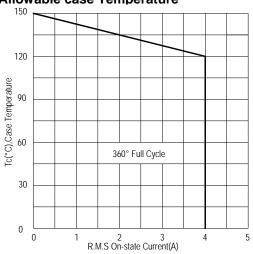


FIG.5: Rated surge on-state current (Non-Repetitive)

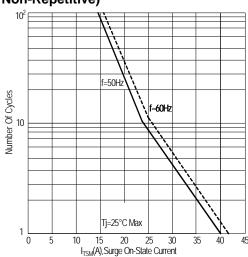


FIG.6: Gate trigger current VS Junction temperature

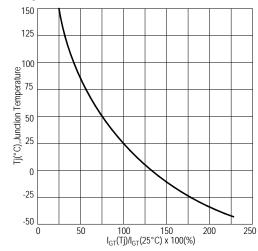






FIG.7:Holding current and Latching current VS Junction temperature

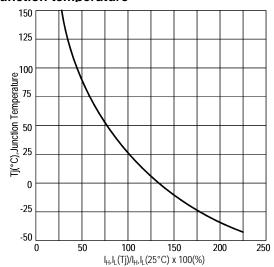
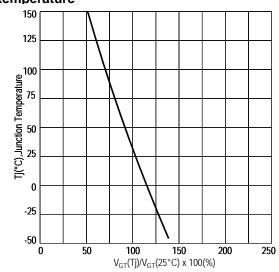
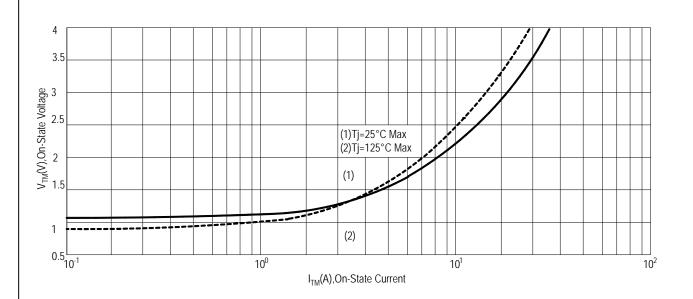


FIG.9: On-state characteristics(Max)

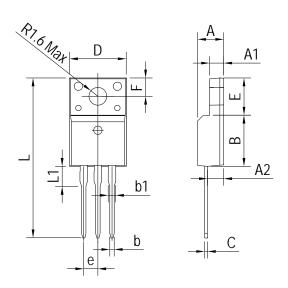
FIG.8: Gate trigger voltage VS Junction temperature





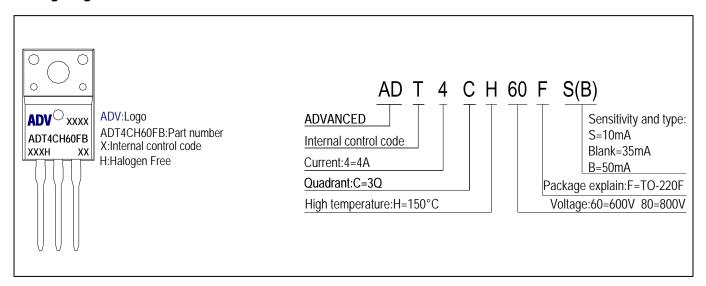


PACKAGE MECHANICAL DATA TO-220F Package Dimension



	Dimens	sions In	Dimensions In			
Symbol	Millimeters		Inches			
	Min	Max	Min	Max		
Α	4.300	4.800	0.169	0.189		
A1	2.400	2.700	0.094	0.106		
A2	2.500	3.000	0.098	0.118		
В	8.800	9.300	0.346	0.367		
b	0.600	0.950	0.023	0.037		
b1	1.100	1.700	0.043	0.067		
С	0.500	0.750	0.020	0.030		
D	9.700	10.360	0.382	0.408		
Е	6.400	6.800	0.252	0.268		
е	2.540 TYP		0.100 TYP			
F	3.300 REF		0.130 REF			
L	28.000	30.000	1.102	1.181		
L1	2.900	3.630	0.114	0.143		

Making Diagram



Ordering information

Part number	number Package Marking		Packing	Quantity		
ADT4CH60F#	TO-220F	ADT4CH60F#	Tube	50pcs		
ADT4CH80F#	TO-220F	ADT4CH80F#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADT4CH60F/80F

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